

07-20-00

JC862 U.S. PTO  
07/19/00JC813 U.S. PTO  
09/619738  
07/19/00UTILITY  
PATENT APPLICATION  
TRANSMITTALOur Docket No.: **169.12-0432**Date: **July 19, 2000**First Named Inventor: **Victor B. Sapozhnikov**Express Mail No.: **EL 212 541 613 US**

## APPLICATION ELEMENTS

## ADDRESS TO:

Assistant Commissioner for Patents  
Box Patent Application  
Washington, D.C. 20231

1. ☒ Fee Calculation Sheet  
(Submit an original and a duplicate for fee processing)
2. ☒ Specification Total Pages **[13]**
  - Descriptive title of the invention
  - Cross References to Related Applications
  - Statement Regarding Fed. Sponsored R&D
  - Reference to Microfiche Appendix
  - Background of the Invention
  - Brief Summary of the Invention
  - Brief Description of the Drawings (if filed)
  - Detailed Description
  - Claims
  - Abstract of the Disclosure
3. ☒ Drawings (35 U.S.C. 113) Total Sheets **[4]**
4. ☒ Oath or Declaration Total Pages **[2]**
  - a. ☒ Newly Executed (original or copy)
  - b. ☐ Copy from a prior application (37 C.F.R. 1.63(d) - for continuation/divisional with Box 18 completed)

**[Mark Box 5 below]**

  - i. ☐ **DELETION OF INVENTOR(S)**  
Signed statement attached deleting inventor(s) named in the prior application, see 37 C.F.R. 1.63(d)(2) and 1.33(b)
  5. ☐ Incorporation by Reference (useable if Box 4b is checked). The entire disclosure of the prior application, from which a copy of the oath or declaration is supplied under Box 4b, is considered as being part of the disclosure of the accompanying application and is hereby incorporated by reference therein

6. ☐ Microfiche Computer Program (Appendix)
7. Nucleotide and/or Amino Acid Sequence Submission  
(If applicable, all necessary)
  - a. ☐ Computer Readable Copy
  - b. ☐ Paper Copy (identical to Computer Copy)
  - c. ☐ Statement verifying identity of above copies

## ACCOMPANYING APPLICATION PARTS

8. ☒ Assignment Papers (cover sheet & document(s))
9. ☐ 37 C.F.R. 3.73(b) Submission
- ☐ Power of Attorney
10. ☐ English Translation Document (if applicable)
11. ☐ Information Disclosure Statement with  
Copies of Citations as necessary
12. ☐ Preliminary Amendment Total Pages ☐
13. ☒ Return Receipt Postcard (Should be specifically itemized)
14. ☐ Small Entity Statement(s)  
☐ Statement filed in Prior Application. Status still proper and desired
15. ☐ Certified Copy of Priority document(s)  
(If foreign priority is claimed)
16. ☒ File Data Sheet
17. ☐ Other

18. If a **CONTINUING APPLICATION**, check appropriate box and supply the requisite information.☐ Continuation ☐ Division ☐ Continuation-in-part (CIP) of prior Application No.

## 19. CORRESPONDENCE ADDRESS

ATTY NAME  
AND REG. NO.**David R. Fairbairn,  
Reg. No. 26,047**

SIGNATURE:



ADDRESS

**Kinney & Lange, P.A.  
THE KINNEY & LANGE BUILDING  
312 South Third Street  
Minneapolis, MN 55415-1002**

TELEPHONE

**(612) 339-1863**

FAX

**(612) 339-6580**

### Inventor Information

Inventor One Given Name :: Victor B.  
 Family Name :: Sapozhnikov  
 Name Suffix ::  
 Postal Address Line One :: 14009 Mount Terrace  
 Postal Address Line Two ::  
 City :: Minnetonka  
 State/Province :: MN  
 Country ::  
 Postal or Zip Code :: 55345  
 City of Residence :: Minnetonka  
 State/Prov. of Residence :: MN  
 Country of Residence ::  
 Citizenship :: Moldova

### Correspondence Information

Name Line One :: David R. Fairbairn  
 Address Line One :: THE KINNEY & LANGE BUILDING  
 Address Line Two :: 312 South Third Street  
 City :: Minneapolis  
 State/Province :: MN  
 Postal or Zip Code :: 55415-1002  
 Telephone :: 612/339-1863  
 Fax :: 612/339-6580  
 E-Mail :: drfairbairn@kinney.com

### Application Information

Title Line One :: THIN FILMS WITH LATERAL COMPOSITION  
 Title Line Two :: MODULATIONS  
 Total Drawing Sheets :: 4  
 Formal Drawings :: Y  
 Application Type :: Utility  
 Docket Number :: I69.12-0432  
 Licensed - U S Government Agency ::  
 Contract Number ::  
 Grant Number ::  
 Secrecy Order in Parent Application ::

### Representative Information

Representative Customer Number :: 00164

## Continuity Information

This application is a ::	Claim benefit of
> Application One ::	60/146,229
Filing Date ::	July 28, 1999
Patent Number ::	
which is a ::	
>> Application Two ::	
Filing Date ::	
Patent Number ::	

006T20"0826T060

## THIN FILMS WITH LATERAL COMPOSITION MODULATIONS

### CROSS-REFERENCE TO RELATED APPLICATION(S)

5 This Application claims priority from provisional application number 60/146,229, filed July 28, 1999 for "Thin Films With Lateral Anisotropic Composition Variations At Atomic Scales" of Victor B. Sapozhnikov.

### BACKGROUND OF THE INVENTION

10 The present invention relates generally to the field of thin films. In particular, the present invention relates to an anisotropic thin film structure having lateral composition modulations at atomic scales.

Thin film structures are widely used in the fields of microelectronics and magnetic data storage and retrieval systems. To impart useful properties onto these thin film structures, the composition of the thin film is commonly varied, or  
15 modulated, at atomic scales throughout the structure. Generally, this composition modulation occurs along a vertical axis of the film. Such vertical composition modulations are created by forming the thin film structure of several thin layers of varying compositions, each layer being only a few Angstroms thick. The resultant thin film structure will have a composition which varies in the direction normal to  
20 the plane of each of the layers.

Less common is a thin film structure having lateral composition modulations; that is, a composition which varies within the plane of the thin film structure itself. Although a multitude of useful applications exist for such thin film structures, the difficulty in consistently producing such structures has generally  
25 precluded their use. Notably, convention shaping methods, such as photolithography, have tolerances which are too great to allow for the controlled creation of a thin film structure having lateral composition modulations at atomic scales. Importantly, a thin film structure having lateral composition modulations would likely have useful anisotropic properties.

Recent years have seen the development of spontaneously-formed structures having lateral composition modulations of certain semiconductor materials. In these spontaneously-formed structures, the lateral composition modulations are coupled to surface morphology in molecular beam epitaxy (MBE) grown short-period superlattices of III-V alloys.

There has also been development in the area of spontaneously-formed giant magnetoresistive multi-layer structures formed of alternating stripes of ferromagnetic and nonferromagnetic metal that are stacked laterally on a special template layer. The template layer is a crystalline structure that has a two-fold uniaxial surface about an axis perpendicular to the surface plane. The alternating stripes of ferromagnetic and nonferromagnetic metal become spontaneously arranged laterally on the template layer during co-deposition.

Such "self-assembled" structures, however, are limited in application to specific materials having the proper crystal structure to spontaneously arrange themselves, or those formed on a specific substrate having the proper crystal structure to cause lateral composition modulations.

Thus, there is a need for a thin film structure having lateral composition variation without the need for "self-assembly".

## BRIEF SUMMARY OF THE INVENTION

A thin film structure has lateral composition modulations. The thin film structure is formed of at least two components. Each of the at least two components is simultaneously deposited in differing directions. Each of the at least two components may also be deposited at differing deposition angles and/or deposition rates.

### BRIEF DESCRIPTION OF THE DRAWINGS

FIGS. 1A, 1B, 1C and 1D are top views of a computer simulated thin film structure in accord with the present invention at four distinct intervals during the structure's formation.

5                    FIGS. 2A, 2B, 2C and 2D are side views of the computer simulated thin film structures of respective FIGS. 1A, 1B, 1C and 1D.

FIG. 3 is a graph displaying correlation functions  $C_{AB}(x)$  and  $C_{AB}(y)$ , as well as correlation anisotropy  $C_{AB}(x) - C_{AB}(y)$ , for a first layer of twenty layers of the thin film structure of FIGS. 1 and 2.

10                   FIG. 4 is a graph displaying correlation functions  $C_{AB}(x)$  and  $C_{AB}(y)$ , as well as correlation anisotropy  $C_{AB}(x) - C_{AB}(y)$ , for a fifteenth layer of twenty layers of the thin film structure of FIGS. 1 and 2.

15                   FIGS. 5A, 5B, 5C and 5D are top views of a computer simulated thin film structure in accord with the present invention at four distinct intervals during the structure's formation.

FIGS. 6A, 6B, 6C and 6D are side views of the computer simulated thin film structure of respective FIGS. 5A, 5B, 5C and 5D.

### DETAILED DESCRIPTION

20                   The present invention is an anisotropic thin film structure having lateral composition modulations which cause the thin film structure to exhibit anisotropic properties. Such a thin film structure can be built by depositing at least two separate components at differing deposition angles, deposition directions and/or deposition rates.

25                   These composition variations, or modulations, result from a natural roughness of a growing film surface. During deposition of a thin film structure, a top surface of the structure will not grow evenly; that is, mounds and valleys in the top surface will form. Thus, if two distinct components A and B were

simultaneously deposited at respective opposing directions east and west, then an eastern side of the mounds would tend to collect more atoms of component A than atoms of component B. Similarly, a western side of the mounds would tend to collect more atoms of component B than atoms of component A. Thus, a ballistic separation of components A and B takes place, a signature of which is created in a growing surface morphology of the thin film structure's composition.

A thin film structure grown in this fashion will have a lateral composition modulation at atomic scales, and an anisotropy in the film's composition since a "north-south" path through the thin film structure will have a composition different than an "east-west" path through the thin film structure. In creating such an anisotropic thin film structure, several other parameters, such as deposition rate, deposition angle, deposition direction and temperature, will have an effect on the composition of the final thin film structure. Of course, more than two components and two deposition directions can be used.

FIGS. 1A, 1B, 1C and 1D are top views of a computer simulated thin film structure in accord with the present invention at four distinct intervals during the structure's formation. FIGS. 2A, 2B, 2C and 2D are side views of the computer simulated thin film structures of respective FIGS. 1A, 1B, 1C and 1D. The thin film structure evolves from only 1 atomic layer in FIGS. 1A and 2A, to 3 atomic layers in FIGS. 1B and 2B, to 10 atomic layers in FIGS. 1C and 2C and finally to 20 atomic layers in FIGS. 1D and 2D.

In this example, the thin film structure is formed by simultaneously sputter-depositing a component A and a component B onto a substrate from opposing directions at equal deposition rates. Component A is deposited at a deposition angle of  $-80^\circ$  with respect to vertical (e.g., normal to the deposition surface) while component B is deposited at a deposition angle of  $80^\circ$  with respect to vertical. Component A is illustrated as being a shade lighter than the substrate, while component B is illustrated as being a shade lighter than component A.

After a single atomic layer has been deposited, portions of the substrate are left uncovered by components A and B. (FIGS. 1A and 2A). Once the thin film structure is built up to three atomic layers, an unevenness of a top surface of the thin film structure has grown more pronounced as mounds and valleys in the top surface begin taking shape and cause the ballistic separation of components A and B. (FIGS. 1B and 2B). As the thin film structure is continued to be built, atoms of components A and B will tend to collect on opposite sides of the mounds, thereby resulting in a lateral composition modulation in the thin film structure. Once the thin film structure is built up to ten atomic layers, the ballistic separation of components A and B is well defined. (FIGS. 1C and 2C). Finally, when the thin film structure has been built up to twenty atomic layers, the anisotropy of the thin film structure's composition is clearly visible as substantially lateral stripes of components A and B are formed in a direction substantially normal to the direction at which components A and B are deposited. (FIGS. 1D and 2D).

FIG. 3 is a graph displaying pair correlation functions  $C_{AB}(x)$  and  $C_{AB}(y)$ , as well as correlation anisotropy  $C_{AB}(x) - C_{AB}(y)$ , for a first of twenty layers of the thin film structure of FIGS. 1D and 2D. FIG. 4 is a similar graph for a fifteenth of twenty layers of the thin film structure of FIGS. 1D and 2D.

One-dimensional pair correlation function  $C_{AB}(x)$  is computed by subtracting the concentration of component B atoms from the probability of finding an atom of component B at a specific distance in the x- direction (the direction of deposition) from an atom of component A. Similarly, one-dimensional pair correlation function  $C_{AB}(y)$  is computed by subtracting the concentration of component B atoms from the probability of finding an atom of component B at a specific distance in the y- direction (normal to the direction of deposition) from an atom of component A.

FIGS. 3 and 4 quantify the anisotropic variation in the thin film structure's composition. The anisotropy of the thin film structure can be evaluated



by comparing the correlation functions in the x- and y-directions. In FIG. 3, each of the one-dimensional correlation functions  $C_{AB}(x)$  and  $C_{AB}(y)$  deviates only a small amount from zero, especially at larger distances. The curves in FIG. 3 indicate that some lateral composition modulation occurs at this first layer, but very little. Accordingly, correlation anisotropy  $C_{AB}(x) - C_{AB}(y)$  also deviates very little from zero.

In FIG. 4, a much more pronounced correlation is visible. The one-dimensional correlation functions  $C_{AB}(x)$  and  $C_{AB}(y)$  differ substantially from one another. At small distances, correlation function  $C_{AB}(y)$  is large for only small distances, and approaches zero for larger distances. This curve illustrates that lateral stripes of components A and B have formed at the fifteenth atomic layer. Correlation function  $C_{AB}(x)$ , on the other hand, is periodic, illustrating that lateral stripes exist at the fifteenth atomic layer. Correlation function  $C_{AB}(x) - C_{AB}(y)$  is a large periodic curve which illustrates the substantial differences between correlation functions  $C_{AB}(x)$  and  $C_{AB}(y)$ .

FIGS. 5A, 5B, 5C and 5D are top views of a computer simulated thin film structure in accord with the present invention at four distinct intervals during the structure's formation. FIGS. 6A, 6B, 6C and 6D are side views of the computer simulated thin film structures of respective FIGS. 5A, 5B, 5C and 5D. The thin film structure evolves from only 1 atomic layer in FIGS. 5A and 6A, to 3 atomic layers in FIGS. 5B and 6B, to 10 atomic layers in FIGS. 5C and 6C and finally to 20 atomic layers in FIGS. 5D and 6D.

In this example, the thin film structure is formed by simultaneously sputter-depositing a component A and a component B onto a substrate from opposing directions at unequal deposition rates and at respective deposition angles of  $-80^\circ$  and  $80^\circ$  with respect to vertical. Component A is deposited at 0.8 atomic layers per second, while component B is deposited at 0.2 atomic layers per second. Component A is deposited at Component A is illustrated as being a shade lighter

than the substrate, while component B is illustrated as being a shade lighter than component A.

These varied deposition rates create an additional effect on the composition of the thin film structure. In addition to the anisotropic composition modulations in each atomic plane, anisotropic correlation occurs in a plane normal to each of the direction of deposition and to the atomic planes. Indeed, because the deposition rates are different, the mounds drift toward the faster-deposition direction as the film grows. This makes the concentration variations lean toward that direction. This effect is most evident in FIGS. 6C and 6D. This effect can be used as another leverage to control magnetic and transport properties of such modulated films.

In generating a thin film structure in accord with the present invention, any or all of the following variables can be varied: number of components, deposition direction of each component, deposition angle of each component, deposition rate of each component, and temperature at which the components are deposited. As shown above, varying the deposition rates can impart composition anisotropy in a vertical plane, as well as a lateral plane.

A thin film structure in accord with the present invention is formed of at least two components. To maximize anisotropy in a lateral plane of the structure, the number of components preferably equals two.

The at least two components are preferably deposited at deposition directions such that an angle formed between deposition directions is greater than zero. More preferably, the angle formed between deposition directions is between about  $90^\circ$  and about  $180^\circ$ . For instance, for a three component thin film structure, the components could be deposited at  $0^\circ$ ,  $120^\circ$  and  $240^\circ$ , such that the deposition direction of each component is separated by  $120^\circ$ . Alternatively, the three components could be deposited at  $0^\circ$ ,  $180^\circ$  and  $270^\circ$ , or any other combination of angles. For a two component system, the angle between the two deposition

directions is preferably equal to about  $180^\circ$ , such that the deposition directions of the two components are substantially opposite one another. In a two component system, as the angle is decreased from  $180^\circ$ , the separation of components (which results in the thin film structure exhibiting lateral composition anisotropy) will be less pronounced.

Also preferred is that the at least two components be deposited at a deposition angle, which is measured with respect to vertical, greater than zero. More preferably, the deposition angle is between about  $\pm 60^\circ$  and about  $\pm 90^\circ$ , and most preferably, as close to  $\pm 90^\circ$  as possible. The angle of the at least two components can vary from one another, or can be equal to one another.

Because temperature at which the components are deposited affects the roughness of a growing thin film structure's top surface, temperature will affect the thin film structure's composition variations. Of interest, as the deposition angle is increased toward  $\pm 90^\circ$ , the surface need be less rough to achieve a well-defined separation between the components in the thin film structure. Conversely, as the angle is decreased from  $\pm 90^\circ$ , the surface needs to be rougher to still allow for well-defined component separation.

In summary, to best achieve lateral composition anisotropy in a thin film structure, it is preferred that two components be deposited from opposite deposition directions (that is,  $180^\circ$  between them), with a deposition angle as close to  $\pm 90^\circ$  as possible. In such a system, as the deposition angle is increased toward  $\pm 90^\circ$ , the angle formed between the deposition directions can stray from  $\pm 180^\circ$  to achieve similar results. Conversely, as the angle formed between deposition directions is increased to  $180^\circ$ , the deposition angle can be reduced.

Imparting atomic-scale lateral composition modulations into a thin film structure may result in novel materials having unusual magnetic transport and crystallographic properties. Several useful applications for such thin film structures having lateral composition modulations exist. For instance, novel thin film

structures having lateral pair ordering anisotropy can be created from combinations of nickel and iron, or from cobalt and platinum, or from cobalt and palladium, or from combinations of rare earth and ferromagnetic materials. Such structures likely have a lateral magnetic anisotropy. Also, novel thin film structures can be composed of combinations of ferromagnetic and paramagnetic materials, or from ferromagnetic and diamagnetic materials. Such thin film structures can have potentially interesting magneto-transport properties. Another interesting application creates laterally layered structures for use as a magnetic core of a write head. A laterally layered magnetic core has ability to suppress harmful eddy currents in the write head. Also, novel thin film structures can be created with alternating conductor and insulating stripes. Such thin film structures have a conductivity in the x-direction substantially different from its conductivity in the y-direction. There may be many other applications.

In conclusion, the present invention is a thin film structure having lateral composition modulations. The thin film structure of the present invention is created by depositing at least two separate components at differing deposition directions, deposition angles, deposition rates and/or temperature.

Although the present invention has been described with reference to preferred embodiments, workers skilled in the art will recognize that changes may be made in form and detail without departing from the spirit and scope of the invention.

## CLAIM(S):

1. A thin film structure having lateral composition modulations, the thin film structure being formed of at least two components, each of which was simultaneously deposited in a different deposition direction.
2. The thin film structure of claim 1 wherein each of the at least two components was deposited at a deposition angle with respect to vertical in a range of about  $\pm 60^\circ$  to about  $\pm 90^\circ$ .
3. The thin film structure of claim 1 wherein each of the at least two components was deposited at a deposition angle with respect to vertical in a range of about  $\pm 75^\circ$  to about  $\pm 90^\circ$ .
4. The thin film structure of claim 1 wherein each of the at least two components was deposited at substantially similar deposition rates.
5. The thin film structure of claim 1 wherein each of the at least two components was deposited at differing deposition rates.
6. The thin film structure of claim 1 wherein angles formed between deposition directions of each of the at least two components was in a range of about  $90^\circ$  to about  $180^\circ$ .
7. An anisotropic thin film structure having a modulated lateral composition, the thin film structure being formed of a first component and a second component, wherein the first component was deposited in a first deposition direction at a first deposition angle and at a first deposition rate, and wherein the

00619738-074900

second component was deposited in a second deposition direction at a second deposition angle and at a second deposition rate, and wherein the second deposition direction varies from the first deposition direction.

8. The anisotropic thin film structure of claim 7 wherein each of the first and second deposition angles is in a range of about  $\pm 75^\circ$  to about  $\pm 90^\circ$  with respect to vertical.

9. The anisotropic thin film structure of claim 7 wherein the first deposition rate substantially equals the second deposition rate.

10. The anisotropic thin film structure of claim 7 wherein each the first deposition rate does not equal the second deposition rate.

11. The anisotropic thin film structure of claim 7 wherein an angle formed between the first and second deposition directions is about  $180^\circ$ .

12. The anisotropic thin film structure of claim 7 wherein the modulation in the lateral composition of the thin film is periodic.

13. A method for imparting lateral composition modulations into a thin film structure, the method comprising:

depositing a first component at a first deposition rate in a first deposition direction at a first deposition angle; and  
simultaneously depositing a second component at a second deposition rate in a second deposition direction at a second deposition angle.

14. The method of claim 13 wherein each of the first and second deposition angles is in a range of about  $\pm 60^\circ$  to about  $\pm 90^\circ$  with respect to vertical.
15. The method of claim 13 wherein each of the first and second deposition angles is in a range of about  $\pm 75^\circ$  to about  $\pm 90^\circ$  with respect to vertical.
16. The method of claim 13 wherein the first deposition rate substantially equals the second deposition rate.
17. The method of claim 13 wherein each the first deposition rate does not equal the second deposition rate.
18. The method of claim 13 wherein an angle formed between the first and second deposition directions is in the range of about  $90^\circ$  to about  $180^\circ$ .
19. The method of claim 13 wherein an angle formed between the first and second deposition directions is about  $180^\circ$ .
20. A thin film structure formed by the method of claim 13.

00619738.071900

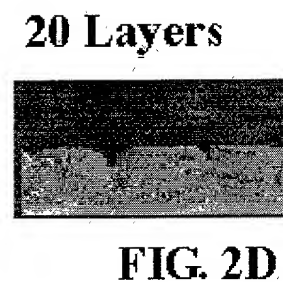
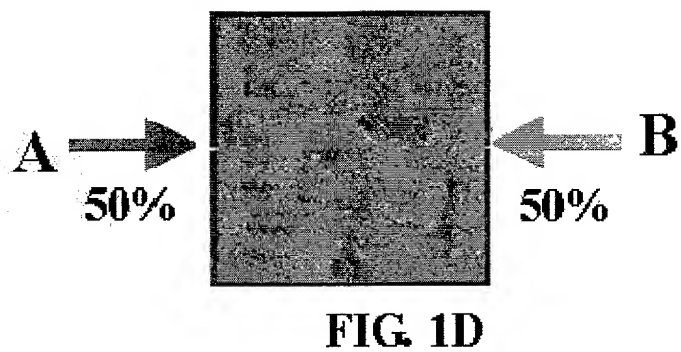
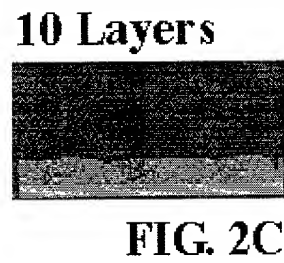
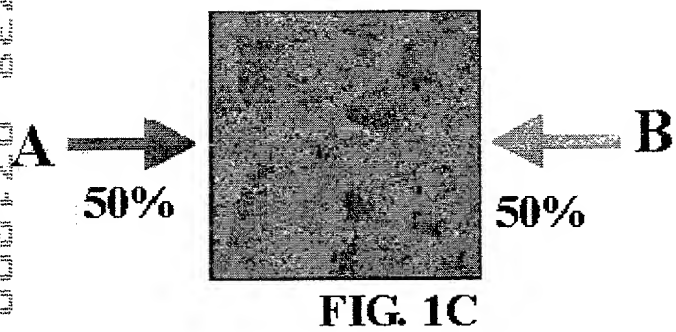
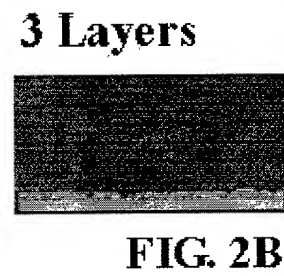
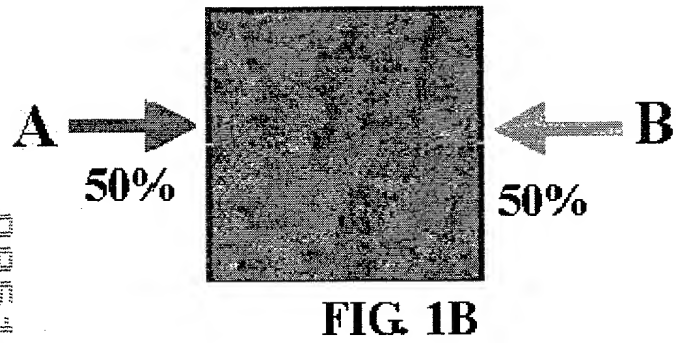
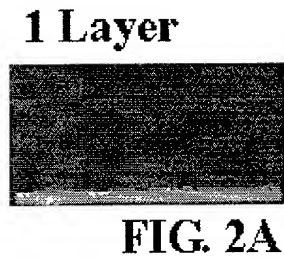
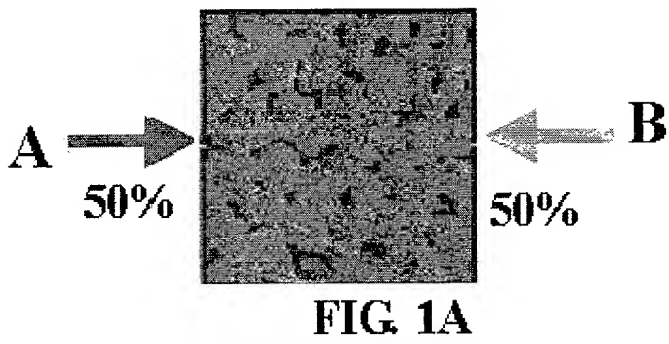
**THIN FILMS WITH LATERAL COMPOSITION MODULATIONS****ABSTRACT OF THE DISCLOSURE**

A thin film structure has lateral composition modulations. The thin film structure is formed of at least two components. Each of the at least two components is simultaneously deposited in differing directions. Each of the at least two components may also be deposited at differing deposition angles and/or deposition rates.

g:\dmk\patfile\69\12.432\applic

006740" 82.67960





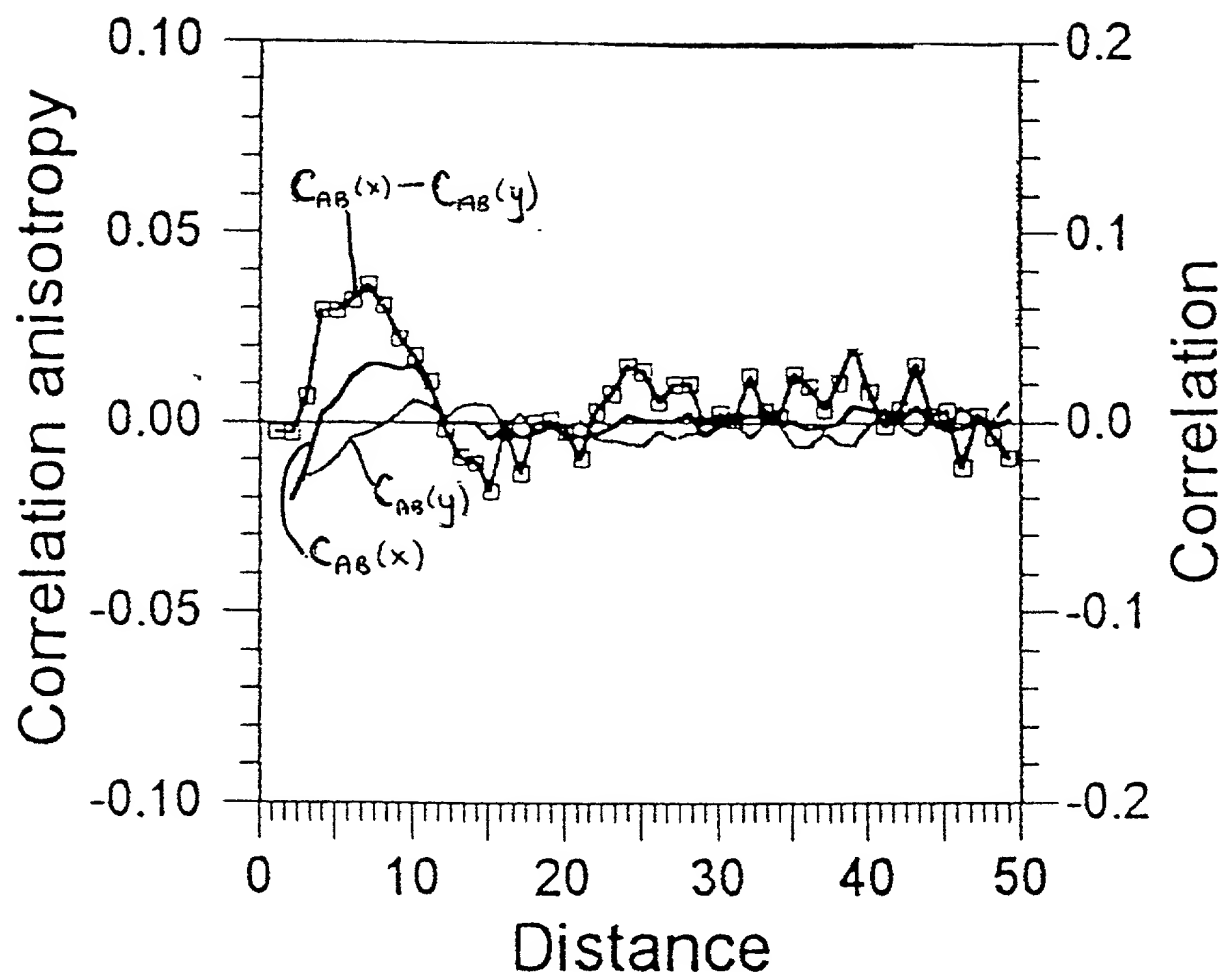
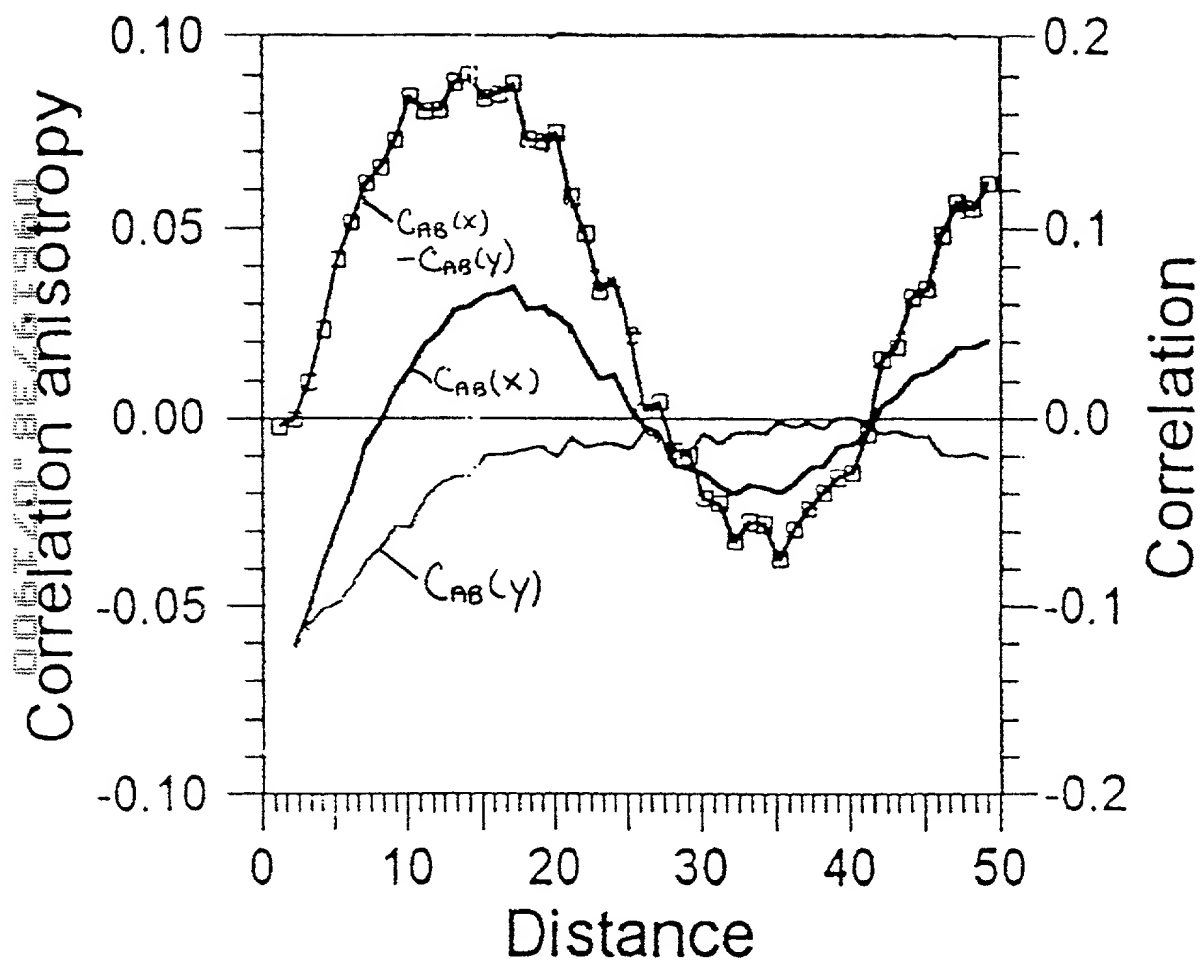
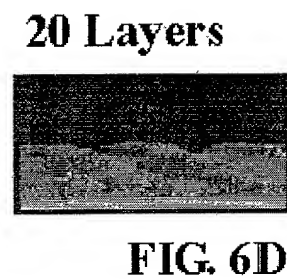
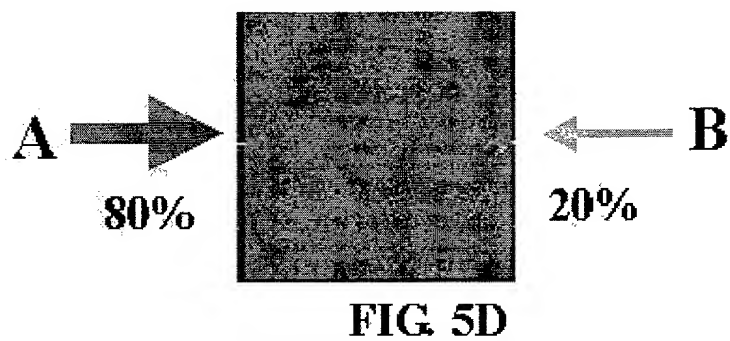
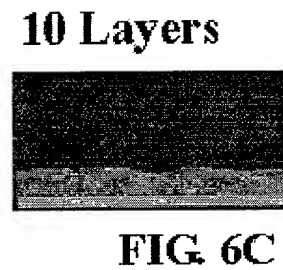
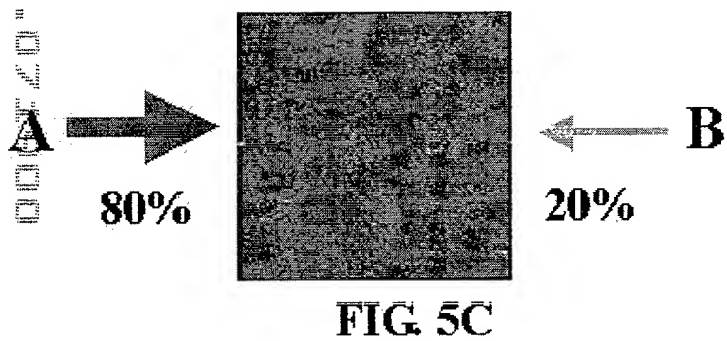
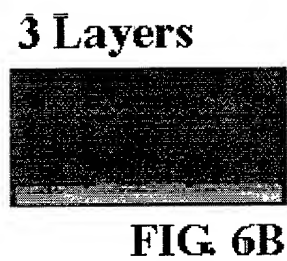
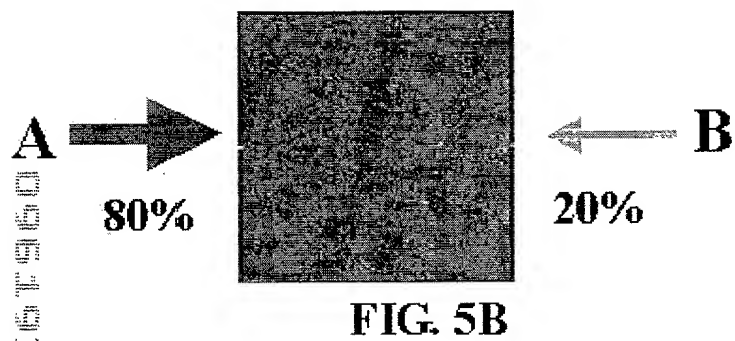
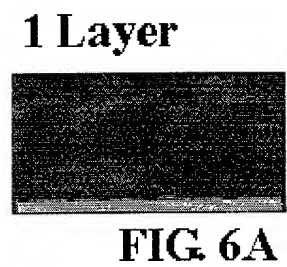
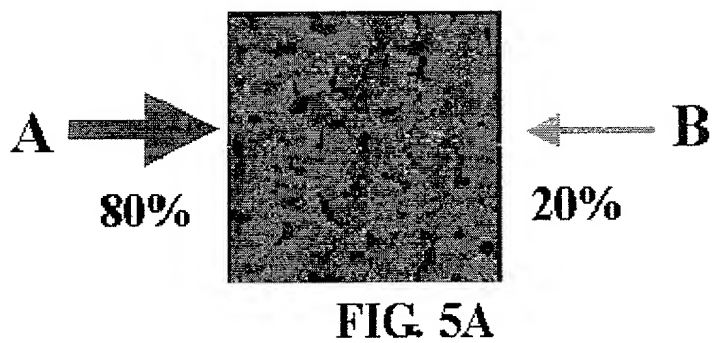


FIG. 3



**FIG. 4**



<b>DECLARATION FOR UTILITY PATENT APPLICATION</b> <b>(37 C.F.R. 1.63)</b>		Attorney Docket No.	I69.12-0432
		First Named Inventor	Victor B. Sapozhnikov
		<b>COMPLETE IF KNOWN</b>	
<input checked="" type="checkbox"/> Declaration Submitted with Initial Filing	<input type="checkbox"/> Declaration Submitted after Initial Filing (Surcharge (37 C.F.R. 1.16(e)) Required)	Application Number	
		Filing Date	
		Group Art Unit	
		Examiner Name	

As a below named inventor, I hereby declare that my residence, post office address, and citizenship are as stated below.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled:  
**THIN FILMS WITH LATERAL COMPOSITION MODULATIONS**

the specification of which:

☒ is attached hereto OR

was filed on \_\_\_\_\_ as United States Application Number \_\_\_\_\_ or PCT International Application Number \_\_\_\_\_ and was amended on \_\_\_\_\_ (if applicable).

I hereby state that I have reviewed and understand the contents of the above identified specification, including the claims, as amended by any amendment specifically referred to above.

I acknowledge the duty to disclose information which is material to patentability as defined in 37 C.F.R. 1.56.

I hereby claim foreign priority benefits under 35 U.S.C. 119(a)-(d) or 365(b) of any foreign application(s) for patent or inventor's certificate, or 365(a) of any PCT international application which designated at least one country other than the United States of America, listed below and have also identified below, by checking the box, any foreign application for patent or inventor's certificate, or of any PCT international application having a filing date before that of the application on which priority is claimed.

Prior Foreign Application Number(s)	Country	Foreign Filing Date (MM/DD/YYYY)	Certified Copy Attached? Yes      No

I hereby claim the benefit under 35 U.S.C. 119(e) of any United States provisional application(s) listed below.

Application Number(s)	Filing Date (MM/DD/YYYY)
60/146,229	July 28, 1999

I hereby claim the benefit under 35 U.S.C. 120 of any United States application(s), or 365(c) of any PCT international application designating the United States of America, listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States or PCT international application in the manner provided by the first paragraph of 35 U.S.C. 112, I acknowledge the duty to disclose information which is material to patentability as defined in 37 C.F.R. 1.56 which became available between the filing date of the prior application and the national or PCT international filing date of this application.

U.S. Parent Application or PCT Parent Number	Parent Filing Date (MM/DD/YYYY)	Parent Patent Number (if applicable)

DIRECT ALL CORRESPONDENCE TO:

Name	David R. Fairbairn
Address	Kinney & Lange, P.A. THE KINNEY & LANGE BUILDING 312 South Third Street Minneapolis, Minnesota 55415 United States
Telephone	(612) 339-1863
Fax	(612) 339-6580

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under 18 U.S.C. 1001 and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

<b>Sole or First Inventor:</b>	
Given Name (First and middle (if any))	Family Name or Surname
Victor B.	Sapozhnikov
Inventor's signature	<i>Victor Sapozhnikov</i> Date: 7-19-00
Residence	Minnetonka, Minnesota      Citizenship: Moldova
Post Office Address	14009 Mount Terrace
City, State, Country	Minnetonka, Minnesota 55345